

P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary (Typ @VGS = -4.5V, TA = +25°C)

| BV _{DSS} | Rds(on) | ID |
|-------------------|--------------------------------|-------|
| 001/ | 37mΩ @ V _{GS} = -4.5V | -4.6A |
| -20V | 49mΩ @ V _{GS} = -2.5V | -3.7A |

Description and Applications

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

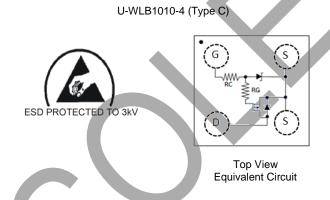
- Battery managements
- Load switches
- Battery protections

Features and Benefits

- Low Qg & Qgd
- Small Footprint
- Low Profile 0.62mm Height
- ESD Protected Up To 3KV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/guality/product-definitions/</u>

Mechanical Data

- Package: U-WLB1010-4
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal: Finish SnAgCu. Solderable per MIL-STD-202 Method 208 ①
- Terminal Connections: See Diagram Below



Ordering Information (Note 4)

| Part Number | Packago | Packing | | |
|---------------|----------------------|---------|-------------|--|
| Part Number | Package | Qty. | Carrier | |
| DMP2042UCB4-7 | U-WLB1010-4 (Type C) | 3000 | Tape & Reel | |

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

| , | 2A | |
|---|----|--|
| | ΥM | |

2A = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: J = 2022)

M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Notes:

| Year | 2016 | | 2022 | 2023 | 2024 | 2025 | 2026 | 2027 | 2028 | 2029 | 2030 | 2031 |
|-------|------|-----|------|------|------|------|------|------|------|------|------|------|
| Code | D | | J | K | L | М | Ν | 0 | Р | R | S | Т |
| | | | | | | | | | | | | |
| Month | Jan | Feb | Mar | Apr | Мау | Jun | Jul | Aug | Sep | Oct | Nov | Dec |



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|---|------------------|-------|------|
| Drain-Source Voltage | VDSS | -20 | V |
| Gate-Source Voltage | V _{GSS} | -6 | V |
| Continuous Drain Current (Note 5) V _{GS} = -4.5V | lD | -4.6 | A |
| Continuous Drain Current (Note 5) V _{GS} = -2.5V | ID | -3.7 | A |
| Pulsed Drain Current (Note 6) | IDM | -16 | A |

Thermal Characteristics

| Symbol | Value | Unit |
|------------------|--------------------------|---|
| PD | 0.75 | W |
| R _{0JA} | 165 | °C/W |
| PD | 1.4 | W |
| Reja | 87 | °C/W |
| TJ, TSTG | -55 to +150 | °C |
| | PD Reja PD Reja | PD 0.75 RøJA 165 PD 1.4 RøJA 87 |

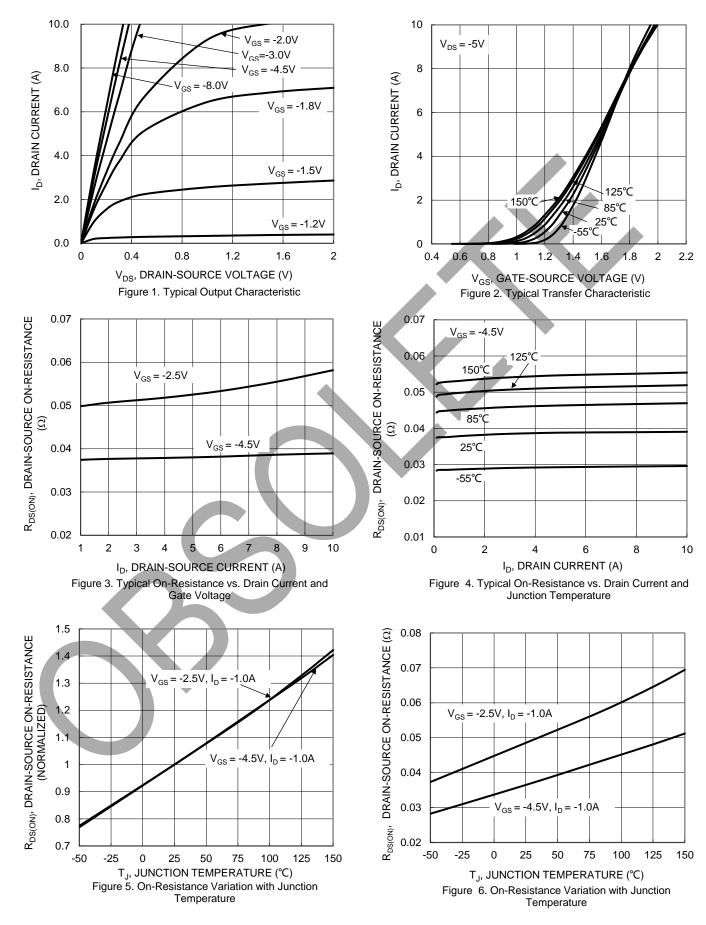
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|---------------------|-------|-------|-------|------|--|--|
| OFF CHARACTERISTICS (Note 8) | Symbol | WIIII | тур | IVIAX | Unit | Test condition | |
| Drain-Source Breakdown Voltage | BVpss | -20 | _ | _ | V | Vgs = 0V, Ip = -250µA | |
| Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$ | IDSS | - | _ | -1 | μA | $V_{DS} = -16V, V_{GS} = 0V$ | |
| Gate-Source Leakage | Igss | | | -100 | nA | $V_{GS} = -6V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 8) | | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | -0.4 | -0.8 | -1.2 | V | $V_{DS} = V_{GS}, I_D = -250 \mu A$ | |
| Otatia Dasia Osuma Os Dasistanas | | | 37 | 45 | | Vgs = -4.5V, Ip =-1A | |
| Static Drain-Source On-Resistance | RDS(ON) | — | 49 | 65 | mΩ | Vgs = -2.5V, ID = -1A | |
| Forward Transfer Admittance | YFS | _ | 6.6 | - | S | V _{DS} = -10V, I _D = -1A | |
| Diode Forward Voltage | Vsd | _ | -0.7 | -1.0 | V | Vgs = 0V, Is = -1A | |
| DYNAMIC CHARACTERISTICS (Note 9) | | | | | | · | |
| Input Capacitance | Ciss | _ | 218 | | | | |
| Output Capacitance | Coss | | 148 | | pF | $V_{DS} = -10V$, $V_{GS} = 0V$, f = 1.0MHz | |
| Reverse Transfer Capacitance | Crss | | 11 | _ | | 1 - 1.00012 | |
| Series Gate Resistance | Rg | | 20 | _ | Ω | f = 1MHz, V _{GS} = 0V, V _{DS} = 0V | |
| Series Clamp Resistance | Rc | | 5,000 | _ | 12 | I = IWHZ, VGS = 0V, VDS = 0V | |
| Total Gate Charge | Qg | | 2.5 | _ | | | |
| Gate-Source Charge | Qgs | — | 0.4 | _ | nC | $V_{GS} = -4.5V, V_{DS} = -10V,$ | |
| Gate-Drain Charge | Q _{gd} | | 0.4 | _ | nc | ID =-1A | |
| Gate Charge at VTH | Qg(TH) | — | 0.2 | _ | | | |
| Turn-On Delay Time | tD(ON) | _ | 0.6 | _ | | | |
| Turn-On Rise Time | tR | — | 0.8 | _ | | V _{DS} = -10V, V _{GS} = -2.5V, | |
| Turn-Off Delay Time | tD(OFF) | _ | 1.4 | — | μs | $R_G = 10\Omega$, $I_D = -1A$ | |
| Turn-Off Fall Time | tF | _ | 0.8 | | | | |
| Reverse Recovery Charge | Q _{RR} | — | 2.2 | _ | nC | $V_{DD} = -10V, I_F = -1.0A,$ | |
| Reverse Recovery Time | t _{RR} | — | 10 | — | ns | di/dt =100A/µs | |

 Device mounted on FR-4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu.
Repetitive rating, pulse width limited by junction temperature.
Device mounted on FR-4 PCB with minimum recommended pad layout, single sided.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing. Notes:



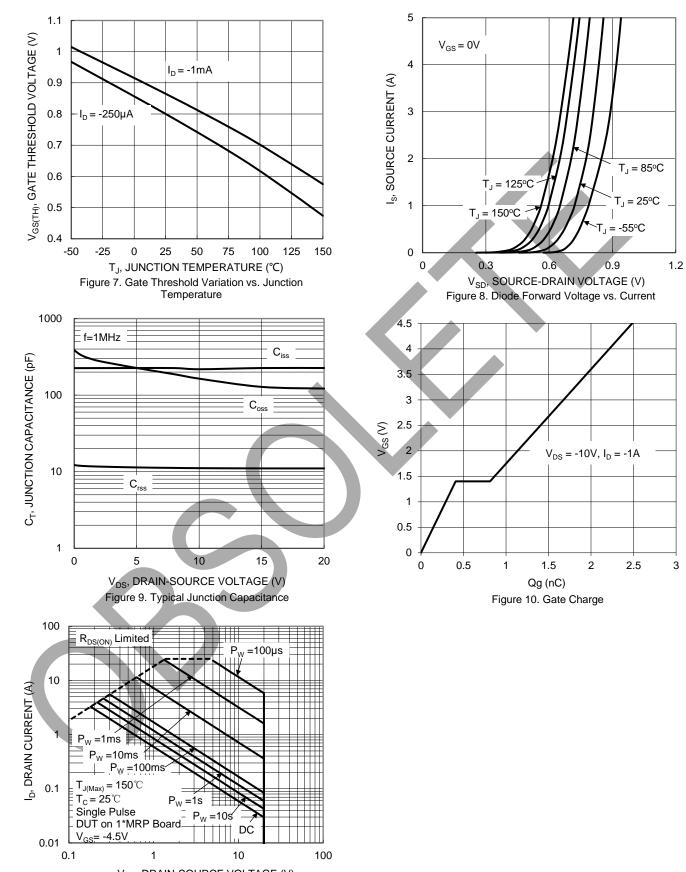
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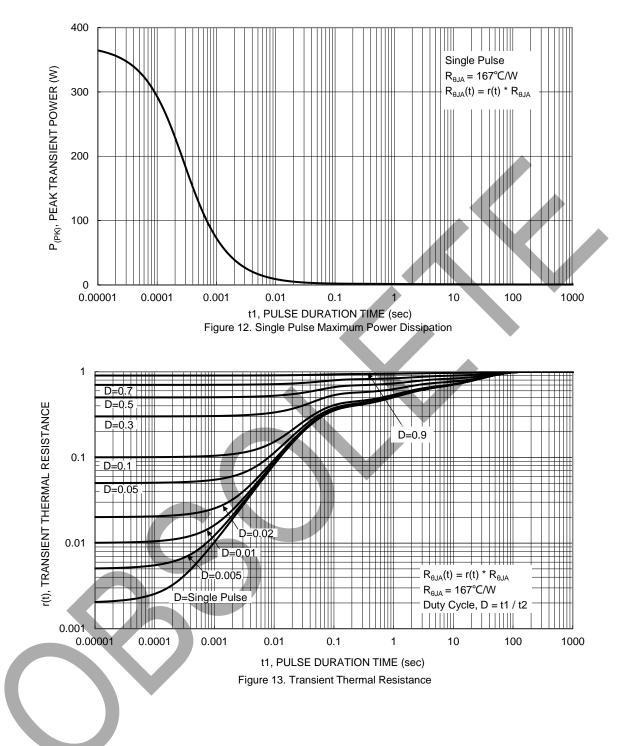
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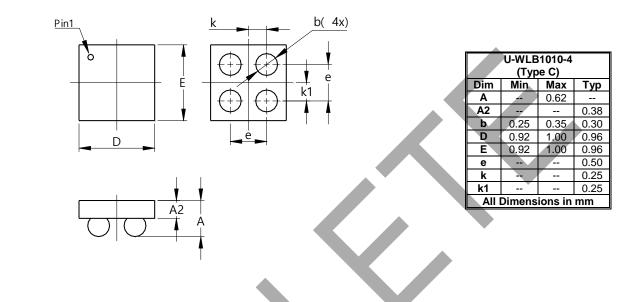




Package Outline Dimensions

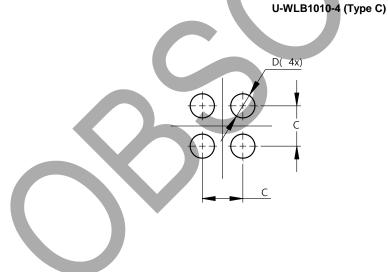
Please see http://www.diodes.com/package-outlines.html for the latest version.

U-WLB1010-4 (Type C)



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



| Dimensions | Value (in mm) |
|------------|------------------|
| С | 0.500 |
| D | 0.300 |



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